# Excellent Integrated System Limited 

Stocking Distributor

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Vishay/Siliconix
DG2735ADN-T1-GE4

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sales@integrated-circuit.com

## Low Voltage, 0.6 , Dual SPDT Analog Switch

## DESCRIPTION

The DG2735A is a low voltage, low on-resistance, dual single-pole/double-throw (SPDT) monolithic CMOS analog switch designed for high performance switching of analog signals. Combining low-power, high speed, low on-resistance, and small package size, the DG2735A, is ideal for portable and battery powered applications.
The DG2735A has an operation range from 1.65 V to 5.5 V single supply. The DG2735A has two separate control pins for independent control of the two SPDT switches.
The DG2735A is guaranteed 1.65 V logic compatible, allowing easy interface with low voltage DSP or MCU control logic and ideal for one cell Li-ion battery direct power.
The switch conducts signals within the power rails equally well in both directions when on, and blocks up to the power supply level when off. Break-before-make is guaranteed.
The DG2735A is built on Vishay Siliconix's sub micron CMOS low voltage process technology and provides greater than 400 mA latch-up protection, as tested per JESD78A.
As a committed partner to the community and the environment, Vishay Siliconix manufactures this product with lead (Pb)-free device terminations. DG2735A is offered in a miniQFN package. The miniQFN package has a nickel-palladium-gold device termination and is represented by the lead (Pb)-free "-GE4" suffix. The nickel-palladium-gold device terminations meet all JEDEC ${ }^{\circledR}$ standards for reflow and MSL ratings.

## FEATURES

- Low voltage operation ( 1.65 V to 5.5 V )
- Low on-resistance - RoN: $0.5 \Omega$ at 2.7 V
- Fast switching: $\mathrm{t}_{\mathrm{ON}}=55 \mathrm{~ns}$ at 2.7 V
- $\mathrm{T}_{\text {Off }}=15 \mathrm{~ns}$ at 2.7 V
- Latch-up current > 400 mA (JESD78)
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912


## BENEFITS

- Reduced power consumption
- High accuracy
- Reduce board space
- TTL/1.65 V logic compatible


## APPLICATIONS

- Cellular phones
- Speaker headset switching
- Audio and video signal routing
- PCMCIA cards
- Battery operated systems
- Portable media players
- Handheld test instruments


## FUNCTIONAL BLOCK DIAGRAM AND PIN CONFIGURATION



Device Marking: Hx for DG2735A
x = Date/Lot Traceability Code

| TRUTH TABLE | NC1, 2 | NO1, 2 |
| :---: | :---: | :---: |
| LOGIC | ON | OFF |
| 0 | OFF | ON |
| 1 |  |  |

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DG2735A
Vishay Siliconix

| ORDERING INFORMATION |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PART NUMBER | CONFIGURATION | SWITCH FUNCTION | TEMP. RANGE | PACKAGE | REEL QUANTITY |  |
| DG2735ADN-T1-GE4 | Dual DPST | NC / NO | $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ | miniQFN10, <br> $1.4 \mathrm{~mm} \times 1.8 \mathrm{~mm}$ | 3000 |  |


| ABSOLUTE MAXIMUM RATINGS ( $\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}$, unless otherwise noted) |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: |
| PARAMETER |  | SYMBOL | LIMIT | UNIT |
| Reference to GND | V+ |  | -0.3 V to +6 V | V |
|  | IN, COM, NC, $\mathrm{NO}^{\text {a }}$ |  | -0.3 V to ( $\mathrm{V}++0.3$ ) |  |
| Current (Any terminal except NO, NC or COM) |  |  | 30 | mA |
| Continuous Current (NO, NC, or COM) |  |  | $\pm 300$ |  |
| Peak Current (Pulsed at $1 \mathrm{~ms}, 10 \%$ duty cycle) |  |  | $\pm 500$ |  |
| Storage Temperature (D Suffix) |  |  | -65 to +150 | ${ }^{\circ} \mathrm{C}$ |
| Power Dissipation (Packages) ${ }^{\text {b }}$ | miniQFN10 ${ }^{\text {c }}$ |  | 208 | mW |
| Latch Up Current |  | JESD78A | >400 | mA |
| ESD - HBM |  | ANSI / ESDA / JEDEC JS-001 | $>5000$ | V |
| ESD - CDM |  | JESD22-C101 | >1000 |  |
| ESD - MM |  | JESD22-A115 | >200 |  |

## Notes

a. Signals on NC, NO, or COM or IN exceeding V+ will be clamped by internal diodes. Limit forward diode current to maximum current ratings.
b. All leads welded or soldered to PC board.
c. Derate $4 \mathrm{~mW} / \mathrm{C}$ above $70^{\circ} \mathrm{C}$.


| SPECIFICATIONS (V+ = 3 V ) |  |  |  |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| PARAMETER | SYMBOL | TEST CONDITIONS UNLESS OTHERWISE SPECIFIED $\mathrm{V}+=3 \mathrm{~V}, \pm 10 \%, \mathrm{~V}$ IN $=0.4 \mathrm{~V}$ or 1.65 V | TEMP. ${ }^{\text {a }}$ | $\begin{gathered} \text { LIMITS } \\ -40^{\circ} \mathrm{C} \text { to }+85^{\circ} \mathrm{C} \end{gathered}$ |  |  | UNIT |
|  |  |  |  | MIN. ${ }^{\text {b }}$ | TYP. ${ }^{\text {c }}$ | MAX. ${ }^{\text {b }}$ |  |
| Digital Control |  |  |  |  |  |  |  |
| Input High Voltage | $\mathrm{V}_{\text {INH }}$ |  | Full | 1.65 | - | - | V |
| Input Low Voltage | $\mathrm{V}_{\text {INL }}$ |  | Full | - | - | 0.4 |  |
| Input Capacitance | $\mathrm{C}_{\text {IN }}$ |  | Full | - | 6 | - | pF |
| Input Current | lint or $\mathrm{linh}^{\text {d }}$ | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}_{+}$ | Full | -1 | - | 1 | $\mu \mathrm{A}$ |
| Dynamic Characteristics |  |  |  |  |  |  |  |
| Break-Before-Make Time ${ }^{\text {e }}$ | $\mathrm{t}_{\text {BBM }}$ | $\begin{gathered} \mathrm{V}_{+}=3.6 \mathrm{~V}, \mathrm{~V}_{\mathrm{NO}}, \mathrm{~V}_{\mathrm{NC}}=1.5 \mathrm{~V}, \mathrm{R}_{\mathrm{L}}=50 \Omega, \\ \mathrm{C}_{\mathrm{L}}=35 \mathrm{pF} \end{gathered}$ | Room | 1 | 15 | - | ns |
| Turn-On Time ${ }^{\text {e }}$ | ${ }^{\text {ton }}$ |  | Room | - | 28 | 78 |  |
|  |  |  | Full | - | - | 80 |  |
| Turn-Off Time ${ }^{\text {e }}$ | toff |  | Room | - | 13 | 58 |  |
|  |  |  | Full | - | - | 60 |  |
| Off-Isolation ${ }^{\text {d }}$ | OIRR | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}, \mathrm{f}=100 \mathrm{kHz}$ | Room | - | -70 | - | dB |
| Crosstalk ${ }^{\text {d }}$ | $\mathrm{X}_{\text {TALK }}$ |  |  | - | -90 | - |  |
| 3dB bandwidth ${ }^{\text {d }}$ |  | $\mathrm{R}_{\mathrm{L}}=50 \Omega, \mathrm{C}_{\mathrm{L}}=5 \mathrm{pF}$ | Room | - | 120 | - | MHz |
| NO, NC Off Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\mathrm{NO} \text { (off) }}$ | $\mathrm{V}_{\mathrm{IN}}=0 \mathrm{~V}$, or $\mathrm{V}+, \mathrm{f}=1 \mathrm{MHz}$ | Room | - | 40 | - | pF |
|  | $\mathrm{C}_{\text {NC( } \text { (ff) }}$ |  |  | - | 40 | - |  |
| Channel On Capacitance ${ }^{\text {d }}$ | $\mathrm{C}_{\mathrm{NO} \text { (on) }}$ |  |  | - | 120 | - |  |
|  | $\mathrm{C}_{\mathrm{NC} \text { (on) }}$ |  |  | - | 120 | - |  |
| Power Supply |  |  |  |  |  |  |  |
| Power Supply Range | V+ |  | - | 1.65 | - | 5.5 | V |
| Power Supply Current | I+ | $\mathrm{V}_{\text {IN }}=0$ or $\mathrm{V}_{+}$ | Full | - | - | 1 | $\mu \mathrm{A}$ |

## Notes

a. Room $=25^{\circ} \mathrm{C}$, Full $=$ as determined by the operating suffix.
b. The algebraic convention whereby the most negative value is a minimum and the most positive a maximum, is used in this data sheet.
c. Typical values are for design aid only, not guaranteed nor subject to production testing.
d. Guarantee by design, not subjected to production test.
e. $\mathrm{V}_{\mathbb{I N}}=$ input voltage to perform proper function.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}\right.$, unless otherwise noted)


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Supply Current vs. Switching Frequency


Switching Threshold vs. Supply Voltage


Switching Time vs. Temperature


Insertion Loss, Off-Isolation Crosstalk vs. Frequency


Supply Current vs. $\mathrm{V}_{\mathrm{IN}}$

## TEST CIRCUITS



Fig. 1 - Switching Time


Fig. 2 - Break-Before-Make Interval

## TEST CIRCUITS




IN depends on switch configuration: input polarity determined by sense of switch.

Fig. 3 - Charge Injection


Fig. 4 - Off-Isolation


Fig. 5 - Channel Off/On Capacitance

[^0]MINI QFN-10L CASE OUTLINE


| DIM | MILLIMETERS |  |  | INCHES |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | MIN. | NAM. | MAX. | MIN. | NAM. | MAX. |
| A | 0.45 | 0.55 | 0.60 | 0.0177 | 0.0217 | 0.0236 |
| A1 | 0.00 | - | 0.05 | 0.000 | - | 0.002 |
| b | 0.15 | 0.20 | 0.25 | 0.006 | 0.008 | 0.010 |
| c | 0.150 or 0.127 REF ${ }^{(1)}$ |  |  | 0.006 or 0.005 REF ${ }^{(1)}$ |  |  |
| D | 1.70 | 1.80 | 1.90 | 0.067 | 0.071 | 0.075 |
| E | 1.30 | 1.40 | 1.50 | 0.051 | 0.055 | 0.059 |
| e | 0.40 BSC |  |  | 0.016 BSC |  |  |
| L | 0.35 | 0.40 | 0.45 | 0.014 | 0.016 | 0.018 |
| L1 | 0.45 | 0.50 | 0.55 | 0.0177 | 0.0197 | 0.0217 |

## Note

(1) The dimension depends on the leadframe that assembly house used.

$$
\begin{aligned}
& \text { ECN T16-0163-Rev. B, 16-May-16 } \\
& \text { DWG: 5957 }
\end{aligned}
$$

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RECOMMENDED MINIMUM PADS FOR MINI QFN 10L


Mounting Footprint
Dimensions in mm (inch)

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